			1			
Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2	("field oxide" near "active area") and field and epitaxial and substrate and gate and transistor and voltage and photodiode and (dop\$4 near region) and spacer and insulat\$4 and block and mask and float\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/22 11:39
S2	0	("field oxide" near active) and field and epitaxial and substrate and gate and transistor and voltage and photodiode and (dop\$4 near region) and spacer and insulat\$4 and block and mask and float\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/22 11:39
S3	0	(oxide near active) and field and epitaxial and substrate and gate and transistor and voltage and photodiode and (dop\$4 near region) and spacer and insulat\$4 and block and mask and float\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/22 11:39
S4	53	oxide and active and field and epitaxial and substrate and gate and transistor and voltage and photodiode and (dop\$4 near region) and spacer and insulat\$4 and block and mask and float\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/22 13:27
S5		"CMOS image sensor" and "spacer insulation layer" and nitride and oxide and angstrom	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/22 13:29
S6	51	"CMOS image sensor" and spacer and nitride and oxide and angstrom	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/22 13:29
S7	157	"CMOS image sensor" and spacer and nitride and oxide and (angstrom near nitride or oxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/22 13:30
S8	374	"CMOS image sensor" and space and (angstrom near nitride or oxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/22 13:30

S9	56	"CMOS image sensor" and (spacer near insulat\$4) and (angstrom near nitride or oxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/22 13:31
S10	85	"CMOS image sensor" and (spacer near4 insulat\$4) and (angstrom near4 nitride or oxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/22 13:30